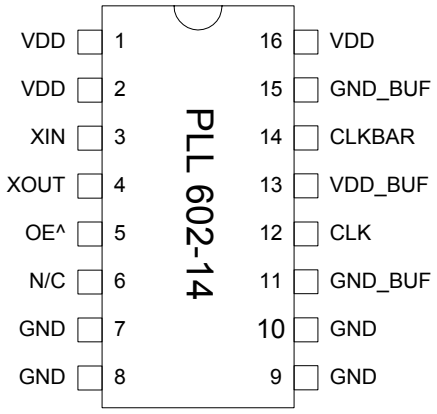
PLL602-14

192MHz – 400MHz Low Phase Noise LVDS XO (12 – 25MHz Crystal)

FEATURES

- Low phase noise output for the 192MHz to 400MHz range (-134 dBc at 10kHz offset).
- LVDS output.
- 12 to 25MHz crystal input.
- Integrated crystal load capacitor: no external load capacitor required.
- Output Enable selector.
- 3.3V operation.
- Available in 16 Pin TSSOP.

PIN CONFIGURATION



Note: ^ denotes internal pull up

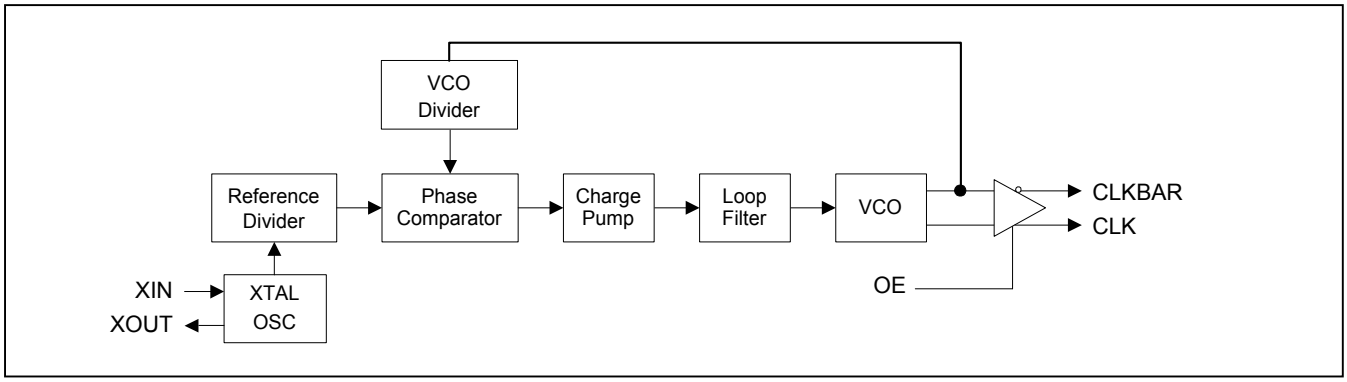
$F_{OUT} = F_{XIN}$ x 16

DESCRIPTION

The PLL602-14 is a monolithic low jitter and low phase noise (-134dBc/Hz @ 10kHz offset) XO IC with LVDS output, for 192MHz to 400MHz output range. It provides a low phase noise reference frequency using a low cost crystal.
The chip delivers an output frequency of F_{XIN} x 16. This makes the PLL602-14 ideal for a wide range of applications.

OE (Pin 5)	Output State
0	Tri-state
1 (Default)	Output enabled

BLOCK DIAGRAM



PIN DESCRIPTIONS

Name	Number	Type	Description
VDD	1,2,16	P	Power supply.
XIN	3	I	Crystal input. See Crystal Specifications on page 2.
XOUT	4	I	Crystal output. See Crystal Specifications on page 2.
OE	5	I	Output enable input. Disables (tri-state) output when low. Internal pull-up enables output by default if pin is not connected to low.
N/C	6	-	Not connected.
GND	7,8,9,10	P	Ground.
GND_BUF	11,15	P	Ground for output buffers.
CLK	12	O	True clock output.
VDD_BUF	13	P	Power supply for output buffers.
CLKB	14	O	Complementary clock output.

ELECTRICAL SPECIFICATIONS

1. Absolute Maximum Ratings

PARAMETERS	SYMBOL	MIN.	MAX.	UNITS
Supply Voltage	V_{DD}		4.6	V
Input Voltage, dc	V_I	-0.5	V_{DD}+0.5	V
Output Voltage, dc	V_O	-0.5	V_{DD}+0.5	V
Storage Temperature	T_S	-65	150	°C
Ambient Operating Temperature*	T_A	-40	85	°C
Junction Temperature	T_J		125	°C
Lead Temperature (soldering, 10s)			260	°C
ESD Protection, Human Body Model			2	kV

Exposure of the device under conditions beyond the limits specified by Maximum Ratings for extended periods may cause permanent damage to the device and affect product reliability. These conditions represent a stress rating only, and functional operations of the device at these or any other conditions above the operational limits noted in this specification is not implied.

* **Note**: Operating Temperature is guaranteed by design for all parts (COMMERCIAL and INDUSTRIAL), but tested for COMMERCIAL grade only.

2. Crystal Specifications

PARAMETERS	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Crystal Resonator Frequency	F_{XIN}	Parallel Fundamental Mode	12		25	MHz
Crystal Loading Rating	$C_{L\ (xtal)}$			20		pF
Recommended ESR	R_E	AT cut			30	Ω

3. General Electrical Specifications

PARAMETERS	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Supply Current, Dynamic (with Loaded Outputs)	I_{DD}	LVDS			60	mA
Operating Voltage	V_{DD}		2.97		3.63	V
Output Clock Duty Cycle		@ 1.25V (LVDS)	45	50	55	%
Short Circuit Current				±50		mA

4. Jitter and Phase Noise Specification

PARAMETERS	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Period jitter RMS	With capacitive decoupling between VDD and GND.		5		ps
Accumulated jitter RMS	With capacitive decoupling between VDD and GND. Over 10,000 cycles.		11		ps
Phase Noise relative to carrier	311MHz @100Hz offset		-90		dBc/Hz
Phase Noise relative to carrier	311MHz @1kHz offset		-114		dBc/Hz
Phase Noise relative to carrier	311MHz @10kHz offset		-134		dBc/Hz
Phase Noise relative to carrier	311MHz @100kHz offset		-134		dBc/Hz

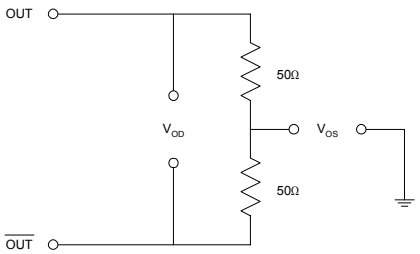
5. LVDS Electrical Characteristics

PARAMETERS	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Output Differential Voltage	V_{OD}	R_L = 100 Ω (see figure)	247	355	454	mV
V_{DD} Magnitude Change	ΔV_{OD}		-50		50	mV
Output High Voltage	V_{OH}			1.4	1.6	V
Output Low Voltage	V_{OL}		0.9	1.1		V
Offset Voltage	V_{OS}		1.125	1.2	1.375	V
Offset Magnitude Change	ΔV_{OS}		0	3	25	mV
Power-off Leakage	I_{OXD}	V_{out} = V_{DD} or GND V_{DD} = 0V		±1	±10	uA
Output Short Circuit Current	I_{OSD}			-5.7	-8	mA

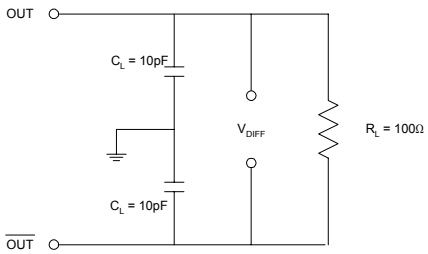
6. LVDS Switching Characteristics

PARAMETERS	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Differential Clock Rise Time	t_r	R_L = 100 Ω C_L = 10 pF (see figure)	0.2	0.7	1.0	ns
Differential Clock Fall Time	t_f		0.2	0.7	1.0	ns

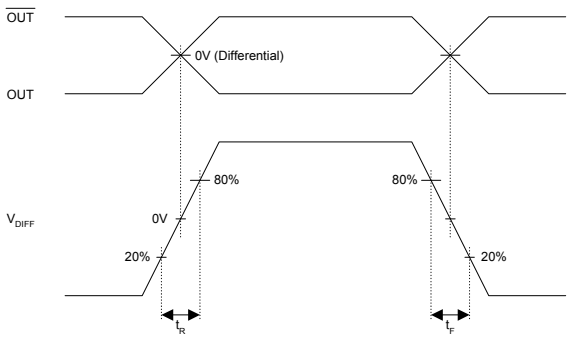
LVDS Levels Test Circuit



LVDS Switching Test Circuit

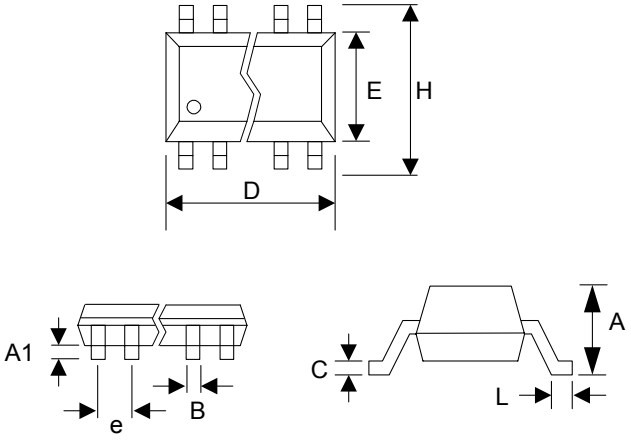


LVDS Transistion Time Waveform



PACKAGE INFORMATION

16 PIN TSSOP (mm)		
Symbol	Min.	Max.
A	-	1.20
A1	0.05	0.15
B	0.19	0.30
C	0.09	0.20
D	4.90	5.10
E	4.30	4.50
H	6.40 BSC	
L	0.45	0.75
e	0.65 BSC	



ORDERING INFORMATION

For part ordering, please contact our Sales Department:
47745 Fremont Blvd., Fremont, CA 94538, USA
Tel: (510) 492-0990 Fax: (510) 492-0991

PART NUMBER
The order number for this device is a combination of the following:
Device number, Package type and Operating temperature range

PLL602-14 S C

PART NUMBER

TEMPERATURE
C=COMMERCIAL
I=INDUSTRAL

PACKAGE TYPE
O=TSSOP

Order Number	Marking	Package Option
PLL602-14OC-R	P602-14OC	TSSOP - Tape and Reel
PLL602-14OC	P602-14OC	TSSOP – Tube